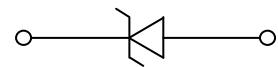


Features

- 1120W peak pulse power ($T_p=8/20\mu s$)
- DFN1610 package
- Fast response time, typically < 1ns
- Excellent clamping voltage
- Low leakage current
- IEC 61000-4-2 ±30kV (Air) ESD protection
- IEC 61000-4-2 ±30kV (Contact) ESD protection
- IEC 61000-4-5 80A (8/20us) SURGE protection
- IEC 61000-4-4 40A (5/50ns) EFT protection
- RoHS compliant



DFN1610



Applications

Schematic Diagram

- USB Vbus
- Power Line
- Power Management

Absolute Maximum Ratings ($T_A=25^\circ C$, unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_p=8/20\mu s$)	P_{PP}	1120	W
Peak Pulse Current ($T_p=8/20\mu s$)	I_{PP}	80	A
Operating Temperature	T_J	-55 To +125	°C
Storage Temperature	T_{STG}	-55 To +150	°C

Electrical Characteristics ($T_A=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse Stand-Off Voltage	V_{RWM}	-	-	-	5	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	6.5	-	-	V
Reverse Leakage Current	I_R	$V_R=5V$	-	-	1.0	µA
Clamping Voltage ¹	V_C	$I_{PP}=80A$	-	14	-	V
Junction Capacitance	C_J	$V_R=0V, f=1MHz$	-	550	-	pF

Note:

1. IEC61000-4-5

Typical Characteristic Curves

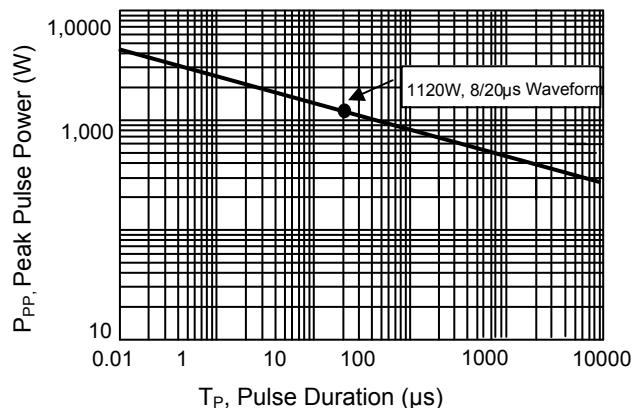


Figure 1. Peak Pulse Power vs. Pulse Time

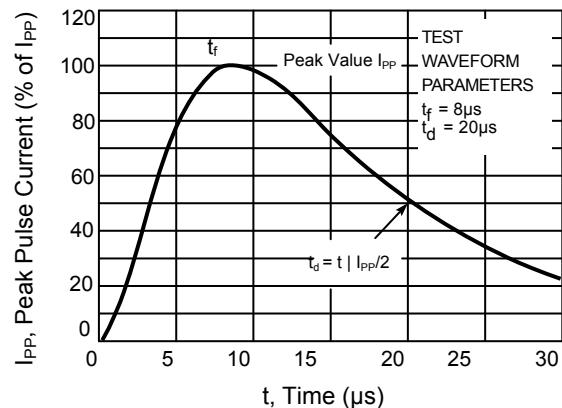


Figure 2. Pulse Waveform - 8/20 μs

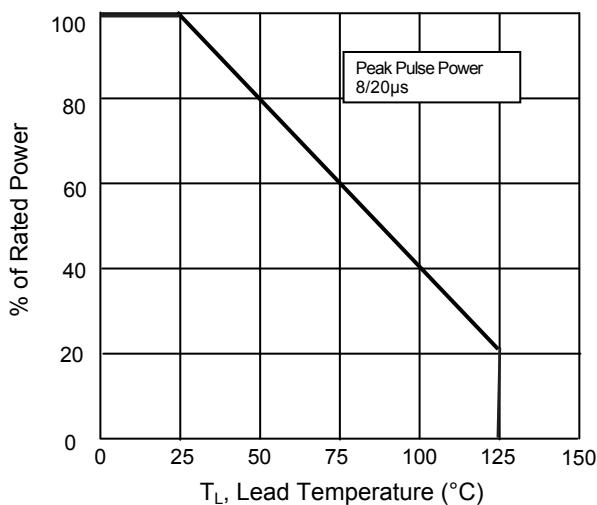


Figure 3. Pulse Derating Curve

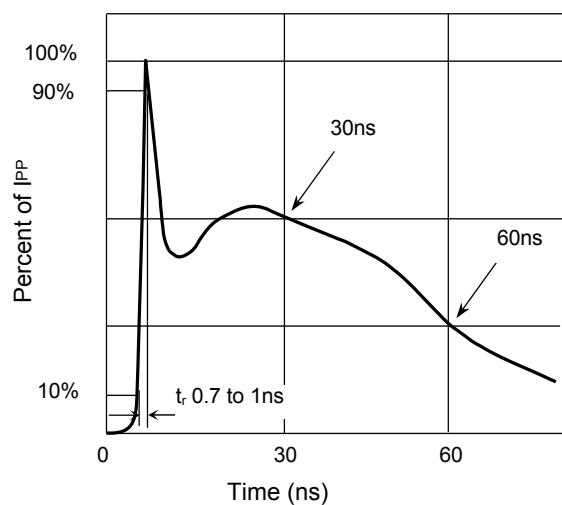
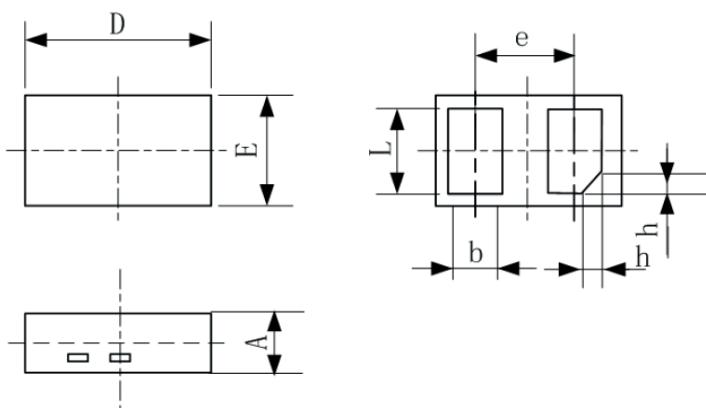


Figure 4. Pulse Waveform - ESD (IEC61000-4-2)

Package Outline Dimensions (DFN1610)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.450	0.550	0.018	0.022
D	1.550	1.650	0.061	0.065
E	0.950	1.050	0.037	0.041
b	0.350	0.450	0.014	0.018
L	0.750	0.850	0.030	0.033
e	1.100 BSC		0.043 BSC	
h	0.150	0.250	0.006	0.010

Order Information

Device	Package	Carrier	Quantity	HSF Status
GSEY5U5500	DFN1610	Tape & Reel	10,000 pcs / Reel	RoHS Compliant